

Low IR Schottky barrier diode

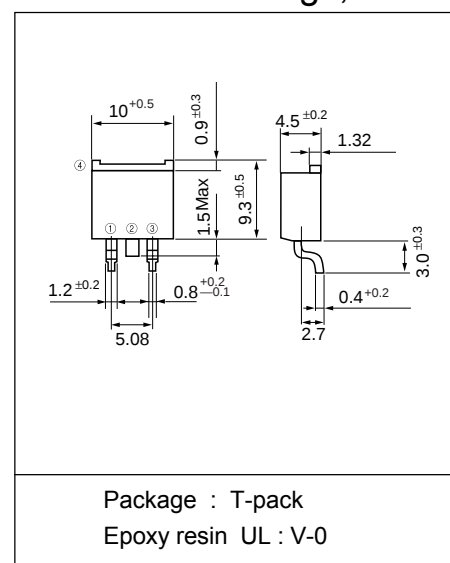
Features

- Low IR
- Low V_F
- Center tap connection

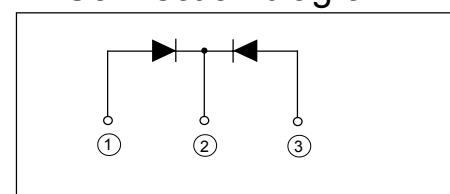
Applications

- High frequency operation
- DC-DC converters
- AC adapter

Outline drawings, mm



Connection diagram



Maximum ratings and characteristics

Maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	V_{RSM}	$t_w=500ns$, duty=1/40	100	V
Repetitive peak reverse voltage	V_{RRM}		100	V
Isolating voltage	Viso	Terminals-to-Case, AC, 1min.	1500	V
Average output current	I_o	Square wave, duty=1/2 $T_c=132^\circ C$	10 *	A
Non-repetitive surge current	I_{FSM}	Sine wave 10ms	125	A
non-repetitive reverse surge power dissipation	PRM	$t_w=10\mu s$, $T_j=25^\circ C$	330	W
Operating junction temperature	T_j		+150	$^\circ C$
Storage temperature	T_{stg}		-40 to +150	$^\circ C$

* Out put current of center tap full wave connection

Electrical characteristics (at $T_a=25^\circ C$ Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage **	V_F	$I_F=5A$	0.86	V
Reverse current **	I_R	$V_R=100V$	150	μA
Thermal resistance	$R_{th(j-c)}$	Junction to case	2.0	$^\circ C/W$

**Rating per element

Mechanical characteristics

Mounting torque	Recommended torque	0.3 to 0.5	N·m
Approximate mass		2	g

(100V / 10A)

TS862C10R (10A)

■ Characteristics

